Schottky Barrier Diode

DB5H411K0L

Unit: mm

Panasonic

DB5H411K0L

Silicon epitaxial planar type

For high frequency rectification DB2J411 in WSMini5 type package

■ Features

- · Low forward voltage and low reverse leakage current
- · Short reverse recovery time trr
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 3F
- Basic Part Number : Dual DB2J411 (Parallel)
- Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

0. 2 0. 13

0. 65)(0. 65)

1. Anode1 4. Cathode2
2. N.C. 5. Cathode1
3. Anode2

Panasonic WSMini5-F1-B

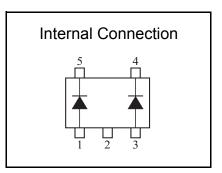
JEITA SC-113CA

Code —

■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Symbol	Rating	Unit
Reverse voltage		VR	40	V
Forward current (Average)	Single	IF(AV)	1	Α
	Double	II-(AV)	0.75	Α
Non-repetitive peak	Single	IFM	3	Α
forward surge current *1	Double	II-IVI	2.25	Α
Junction temperature		Tj	125	°C
Operating ambient temperature		Topr	-40 to +85	°C
Storage temperature		Tstg	-55 to +125	°C

Note: *1 50 Hz sine wave 1 cycle (Non-repetitive peak current)



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Revision . 2

Schottky Barrier Diode

DB5H411K0L

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■ Electrical Characteristics Ta = 25 °C ± 3 °C

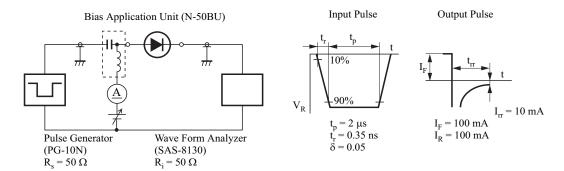
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 1 A		0.50	0.58	V
Reverse current	IR	VR = 40 V		15	100	μA
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		21		pF
Reverse recovery time *1	trr	IF = IR = 100 mA, Irr = 10 mA		6.8		ns

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 3. *1 trr test circuit

Established: 2011-03-23

: 2013-04-26

Revised

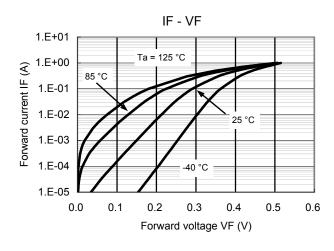


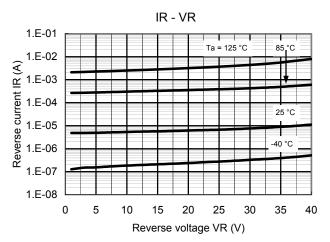
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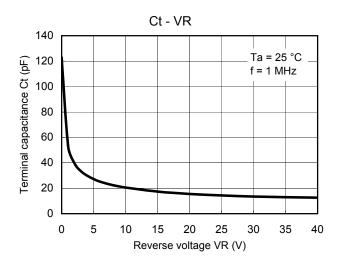
Schottky Barrier Diode

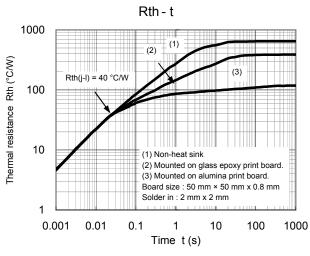
DB5H411K0L

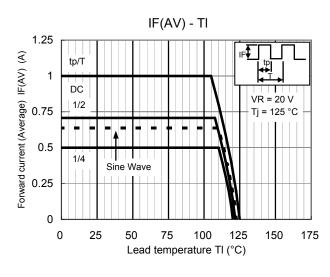
Technical Data (reference)

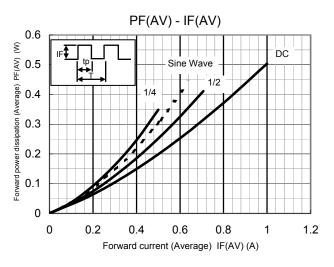












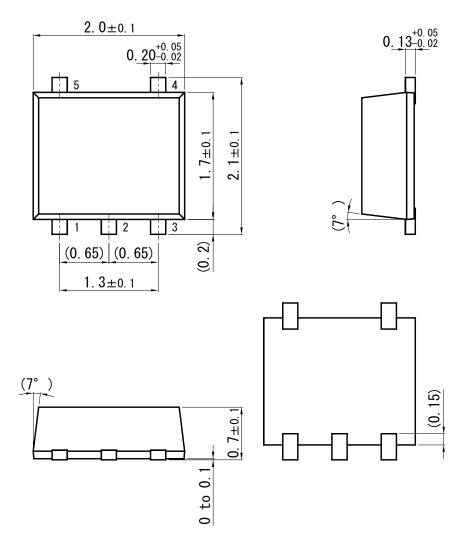
Established: 2011-03-23 Revised: 2013-04-26 **Panasonic**

Schottky Barrier Diode

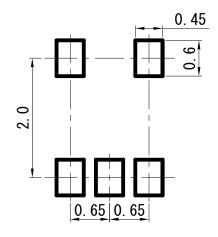
DB5H411K0L

WSMini5-F1-B

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



Established: 2011-03-23 Revised: 2013-04-26

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